

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
L1	11	((dope or doping or doped) near2 (channel adj region)) and (fixed adj charge adj density)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/13 07:54
L2	0	((dope or doping or doped) near2 (channel adj region)) same (fixed adj charge adj density)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/13 07:58
L3	1164	((channel near region) near10 portion near10 (dope or doped or doping or dopant))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/13 07:58
L4	408	((channel near region) near10 portion near10 (dope or doped or doping or dopant)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/13 07:58
L5	21	((tft or (thin adj film)) with ((channel near region) near10 portion near10 (dope or doped or doping or dopant)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/13 07:58
L6	21	((tft or (thin adj film)) with ((channel near region) near10 portion near10 (dope or doped or doping or dopant))).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/13 08:02
L7	5	((tft or (thin adj film)) near5 ((channel near region) near5 portion near5 (dope or doped or doping or dopant))).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/13 08:02
L8	17	((tft or (thin adj film)) near10 ((channel near region) near10 portion near10 (dope or doped or doping or dopant))).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/13 08:10
L9	3	((tft or (thin adj film)) near10 ((channel near region) near10 portion near10 (dope or doped or doping or dopant))).clm. and (channel near5 (dope or doped or doping or dopant)).ab.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/13 08:05

L10	0	l4 and ((zno or (zinc near oxide)) near5 channel)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/13 08:05
L11	0	l4 and ((zno or (zinc near oxide)) near10 channel)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/13 08:05
L12	110	(fixed near2 charge near2 density) and (tft or (thin adj film adj transistor))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/13 08:11
L13	110	(fixed near2 charge near2 density) and (tft or (thin adj film adj transistor) or (thin near film near channel))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/13 08:11
L14	4	(fixed near2 charge near2 density) near10 (tft or (thin adj film adj transistor) or (thin near film near channel))	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/13 08:12
L15	1	(fixed near2 charge near2 density) near10 (tft or (thin adj film adj transistor) or (thin near film near channel)) with (dope or doped or doping or dopant)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/13 08:12
L16	1	(fixed near2 charge near2 density) with (tft or (thin adj film adj transistor) or (thin near film near channel)) with (dope or doped or doping or dopant)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2004/12/13 08:12